

TOSHIBA Field Effect Transistor Silicon P Channel Junction Type

2SJ104

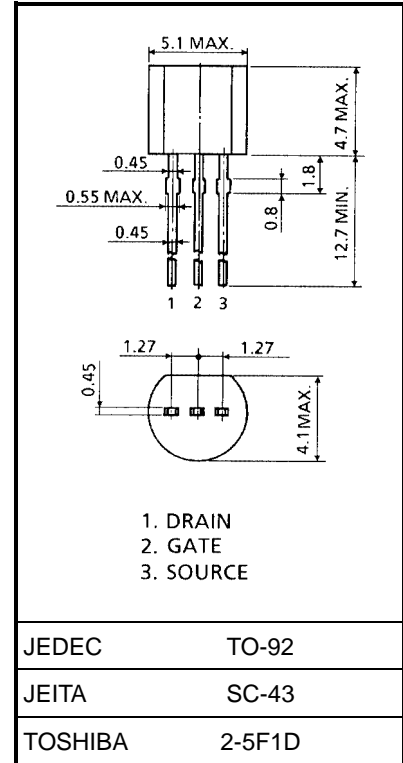
For Audio Amplifier, Analog Switch, Constant Current and Impedance Converter Applications

Unit: mm

- High input impedance: $I_{GSS} = 1.0 \text{ nA (max)} (V_{GS} = 25 \text{ V})$
- Low $R_{DS(ON)} = 40 \text{ } \Omega \text{ (typ.)} (I_{DSS} = -5 \text{ mA})$
- Complimentary to 2SK364

Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	V_{GDS}	25	V
Gate current	I_G	-10	mA
Drain power dissipation	P_D	400	mW
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55~125	$^\circ\text{C}$



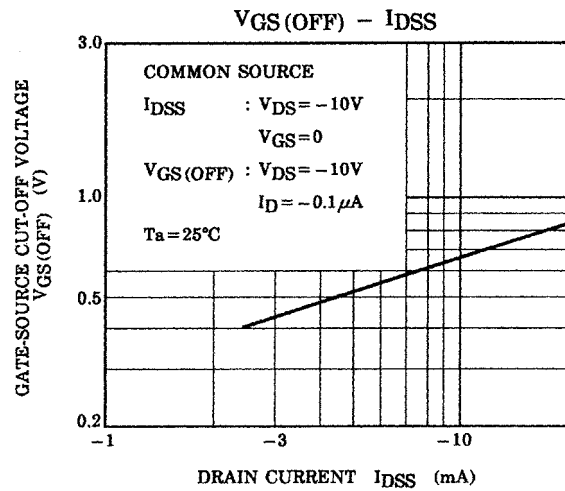
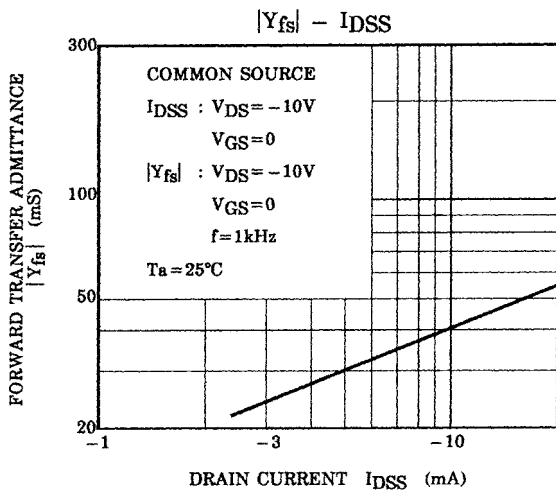
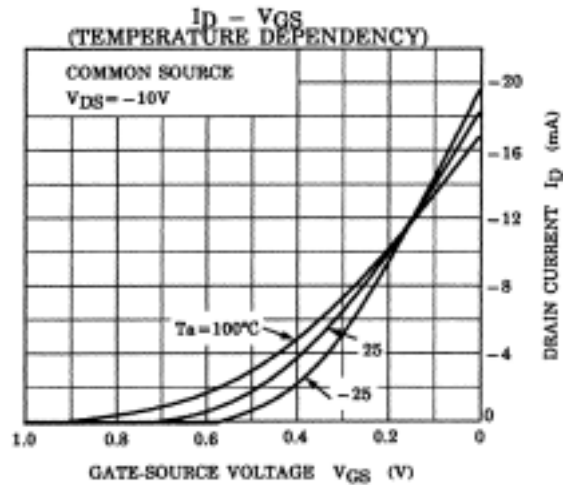
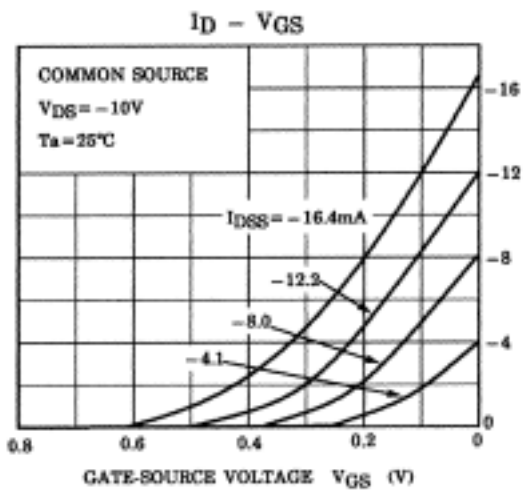
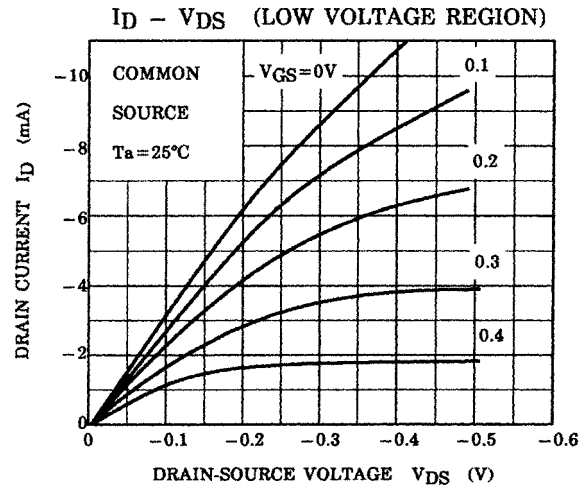
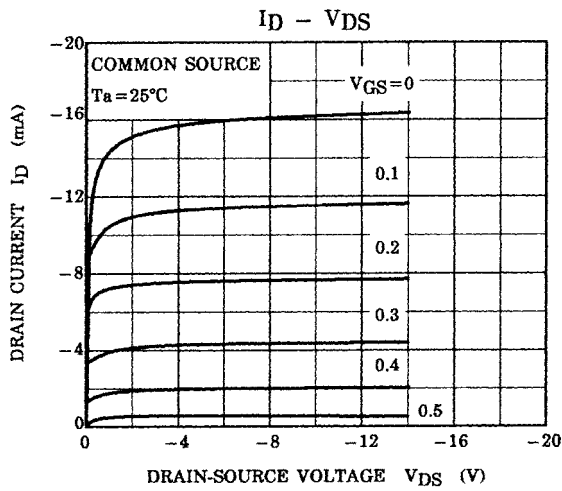
Weight: 0.21 g (typ.)

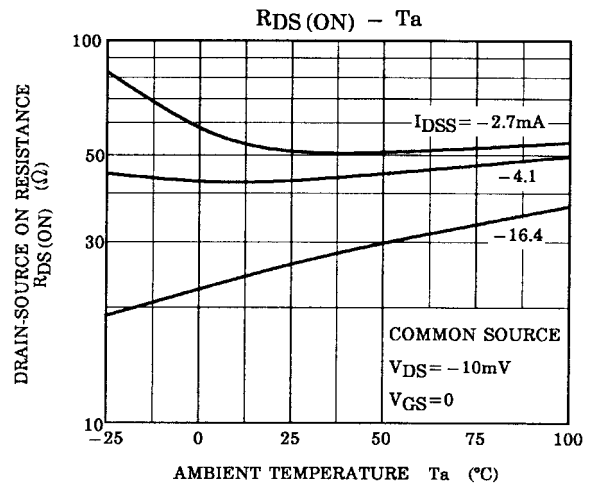
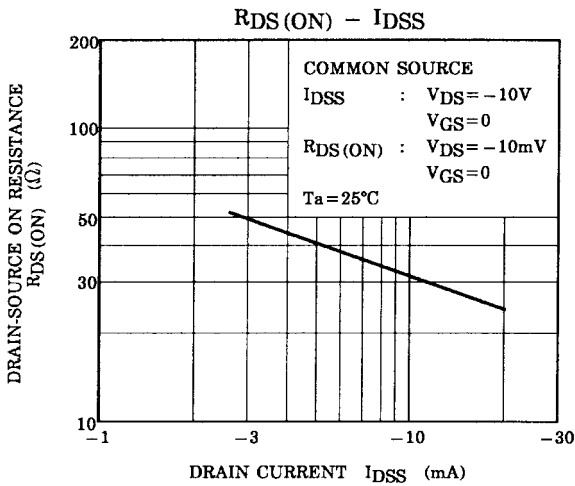
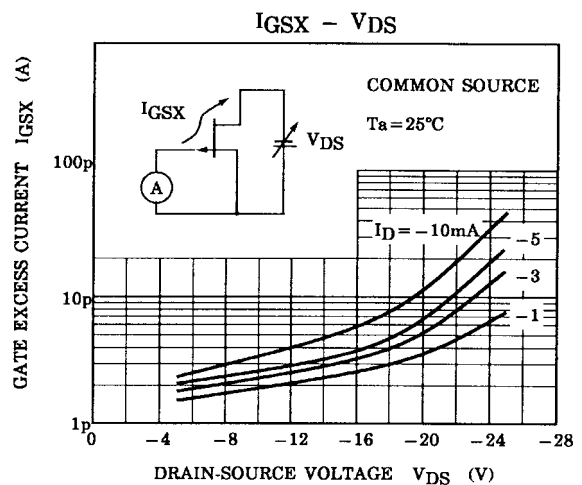
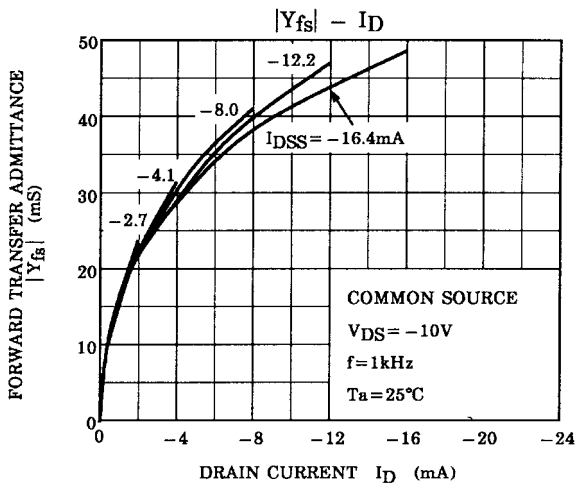
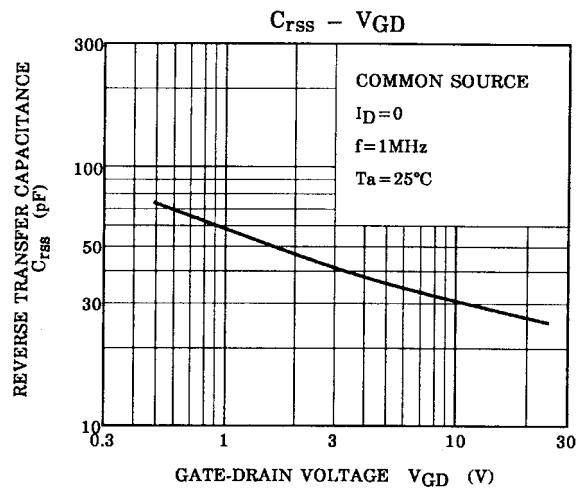
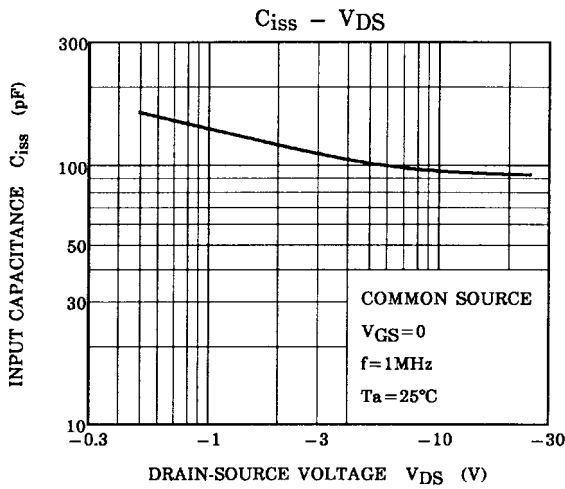
Electrical Characteristics ($T_a = 25^\circ\text{C}$)

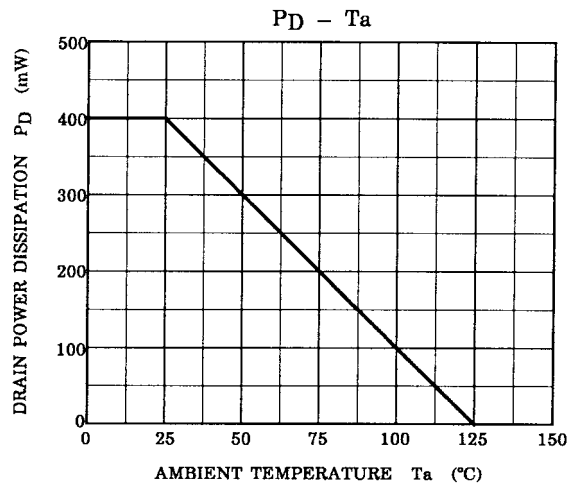
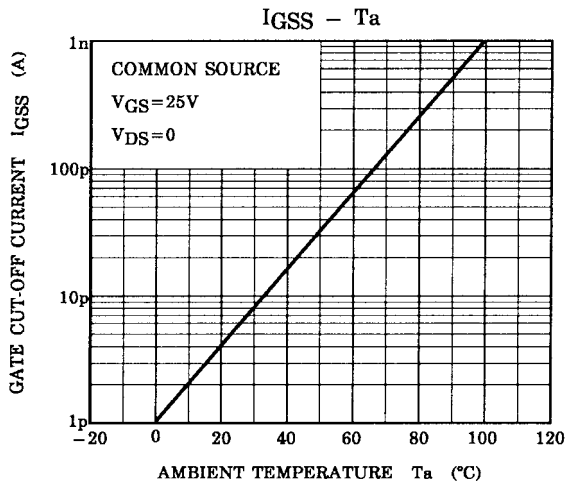
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate cut-off current	I_{GSS}	$V_{GS} = 25 \text{ V}, V_{DS} = 0$	—	—	1.0	nA
Gate-drain breakdown voltage	$V_{(BR) GDS}$	$V_{DS} = 0, I_G = 100 \text{ } \mu\text{A}$	25	—	—	V
Drain current	I_{DSS} (Note 1)	$V_{DS} = -10 \text{ V}, V_{GS} = 0$	-2.6	—	-20	mA
Gate-source cut-off voltage	$V_{GS(OFF)}$	$V_{DS} = -10 \text{ V}, I_D = -0.1 \text{ } \mu\text{A}$	0.2	—	2.0	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$ (Note 2)	12	30	—	mS
Input capacitance	C_{iss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	—	105	—	pF
Reverse transfer capacitance	C_{rss}	$V_{DG} = -10 \text{ V}, I_D = 0, f = 1 \text{ MHz}$	—	32	—	pF
Drain-source ON resistance	$R_{DS(ON)}$	$V_{DS} = -10 \text{ mV}, V_{GS} = 0$ (Note 2)	—	40	—	Ω

Note 1: I_{DSS} classification GR: -2.6~-6.5 mA, BL: -6~-12 mA, V: -10~-20 mA

Note 2: Condition of the typical value $I_{DSS} = -5 \text{ mA}$







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